

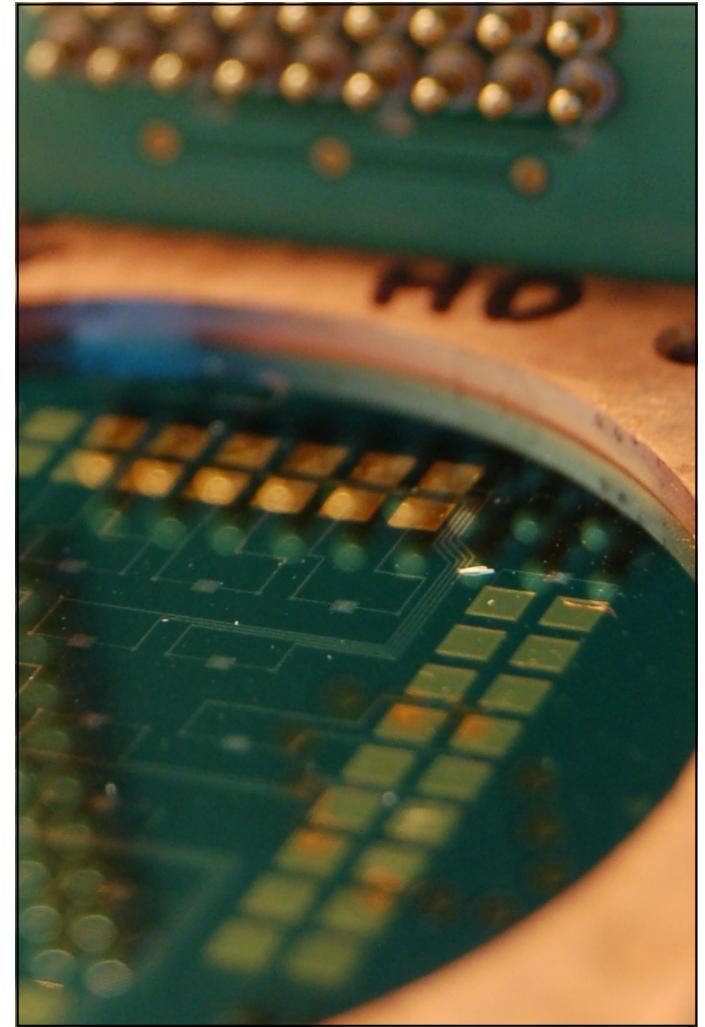
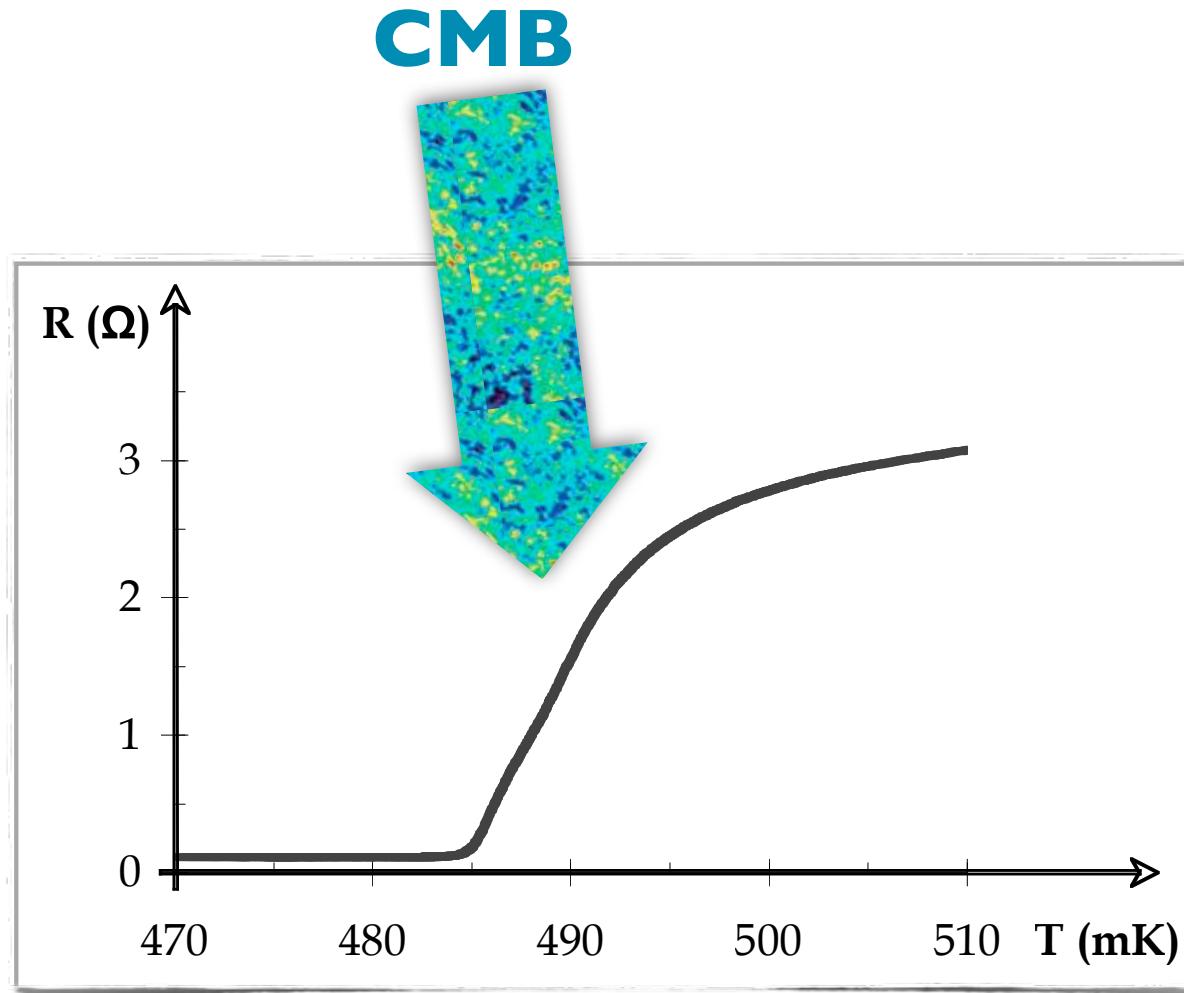


SQUID Multiplexing Control

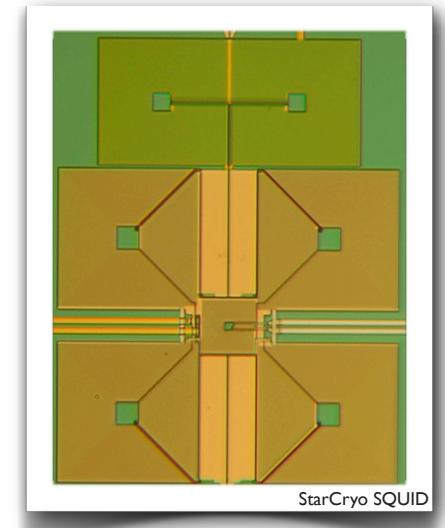
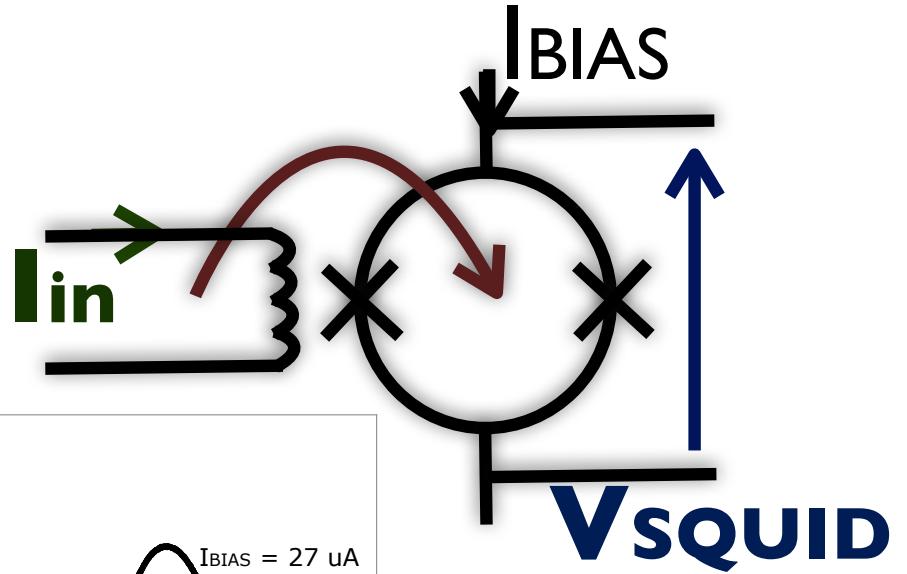
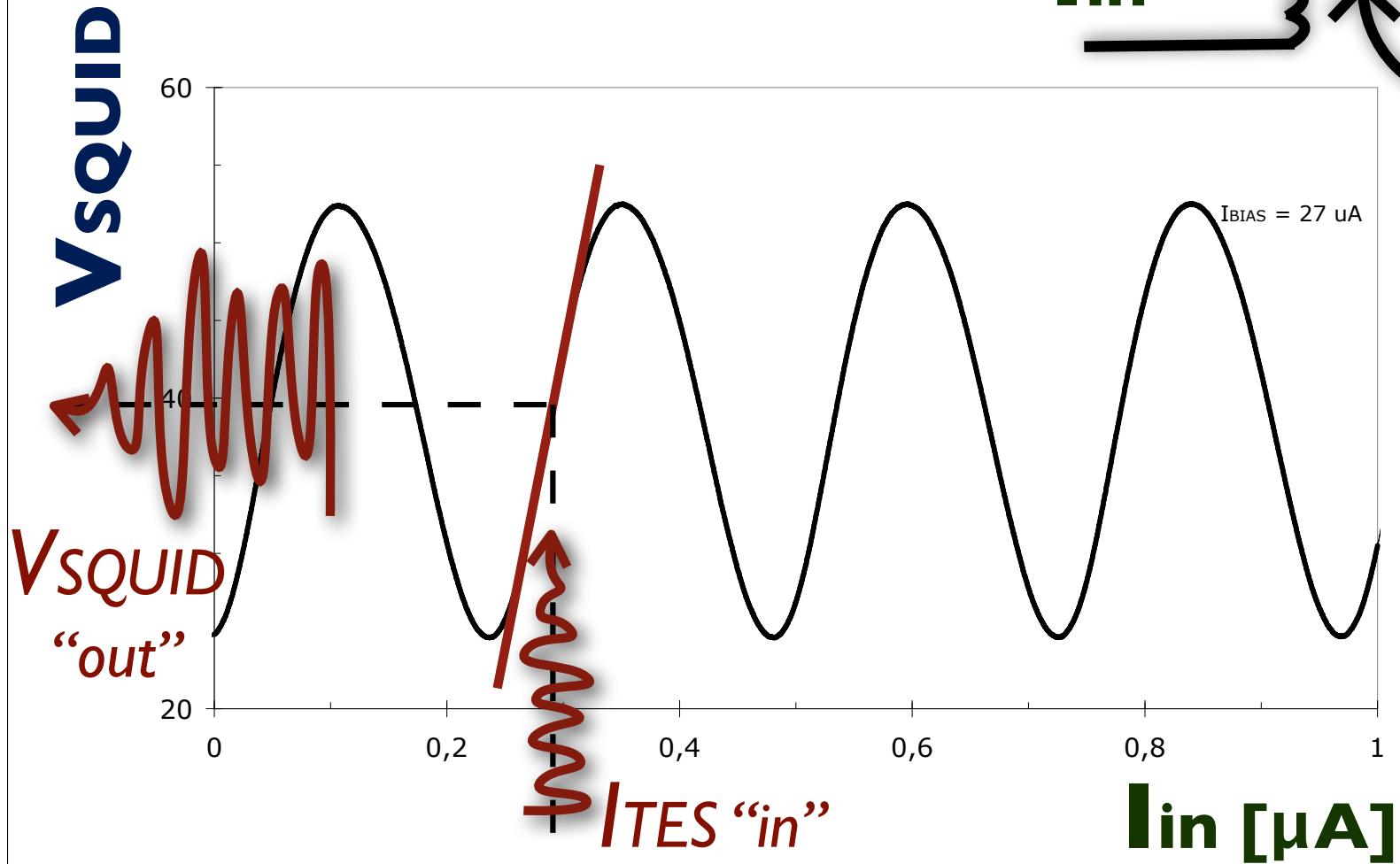
D. Prêle, F. Voisin

Ecole Micro-électronique - La Londe - Oct. 09

Sensor : TES (superconducting bolometer)

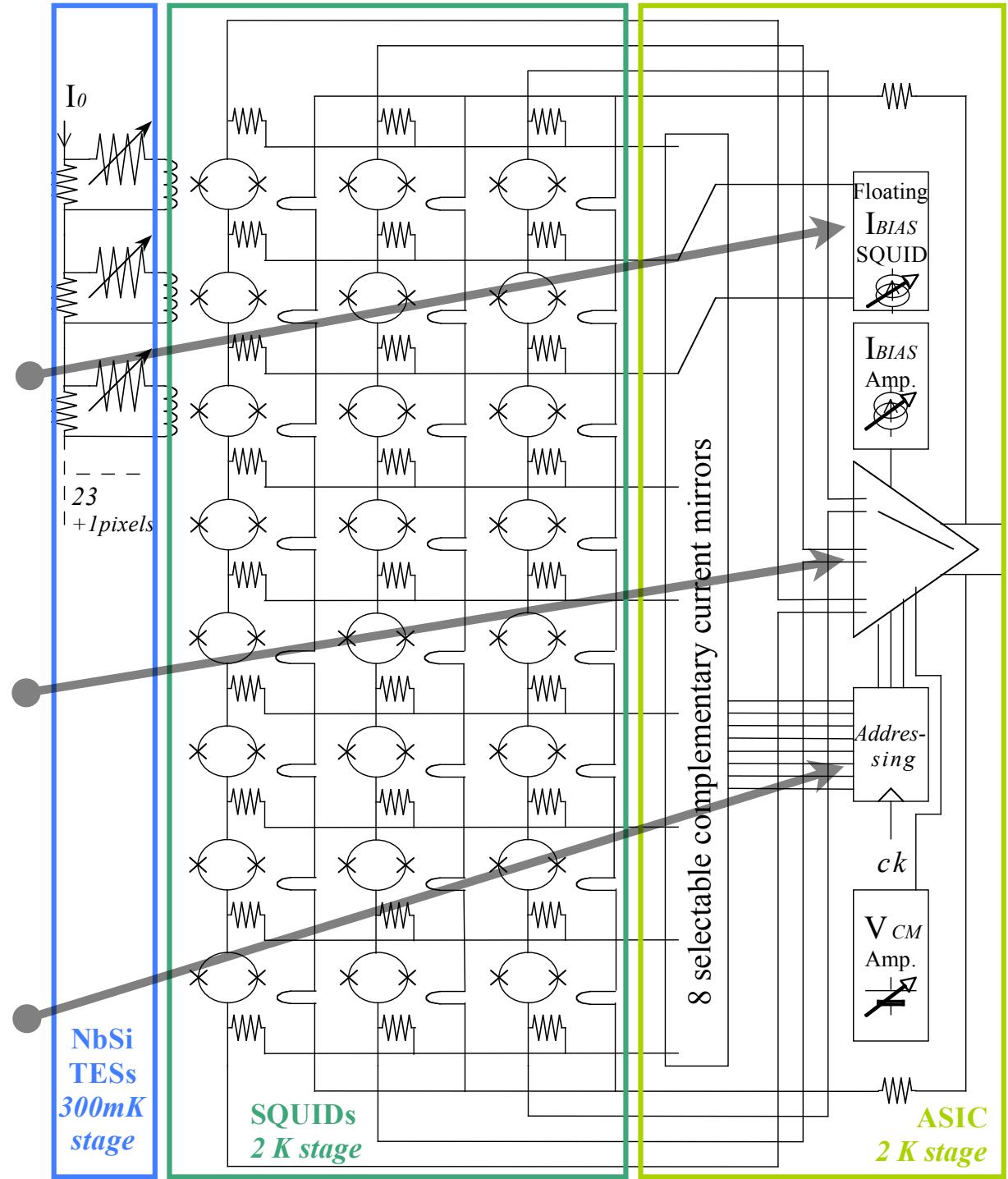


First readout : SQUID

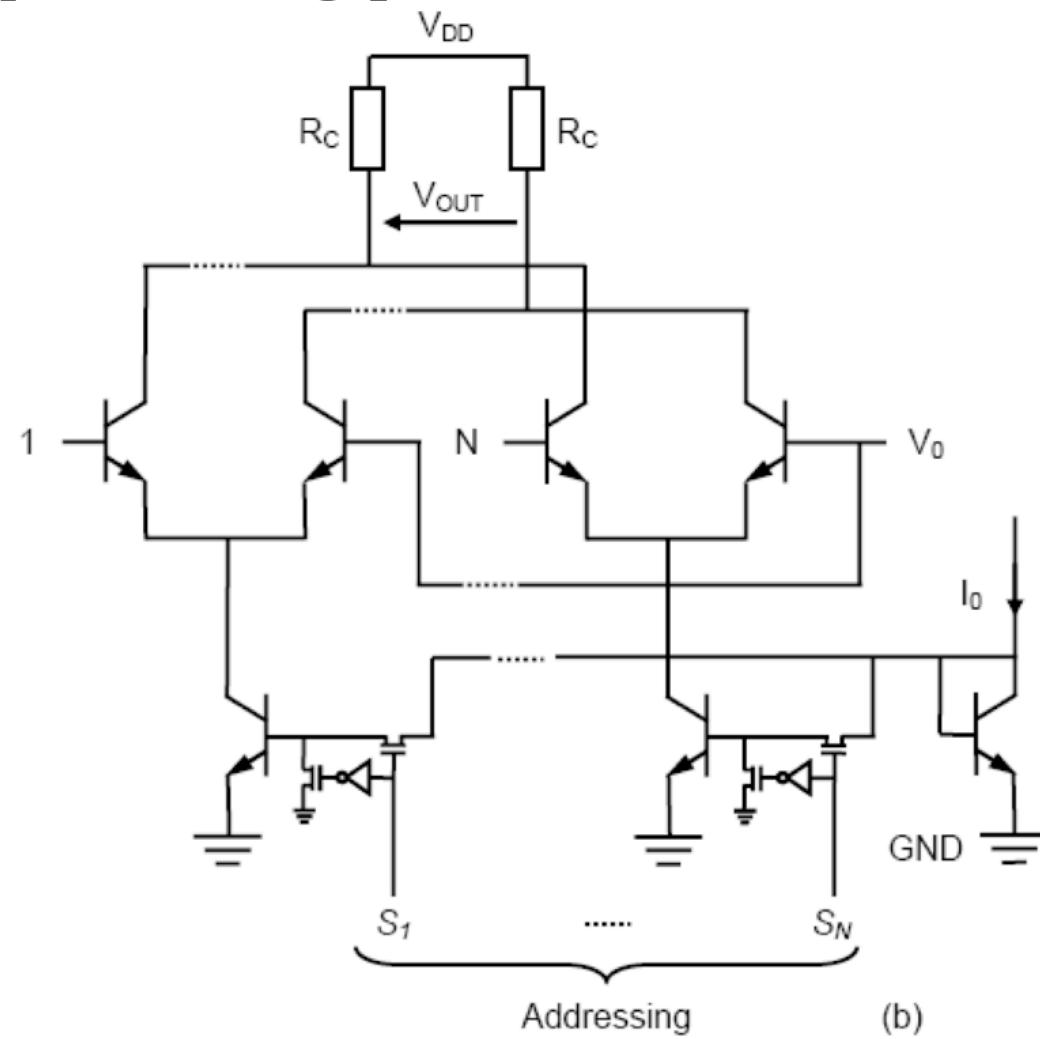
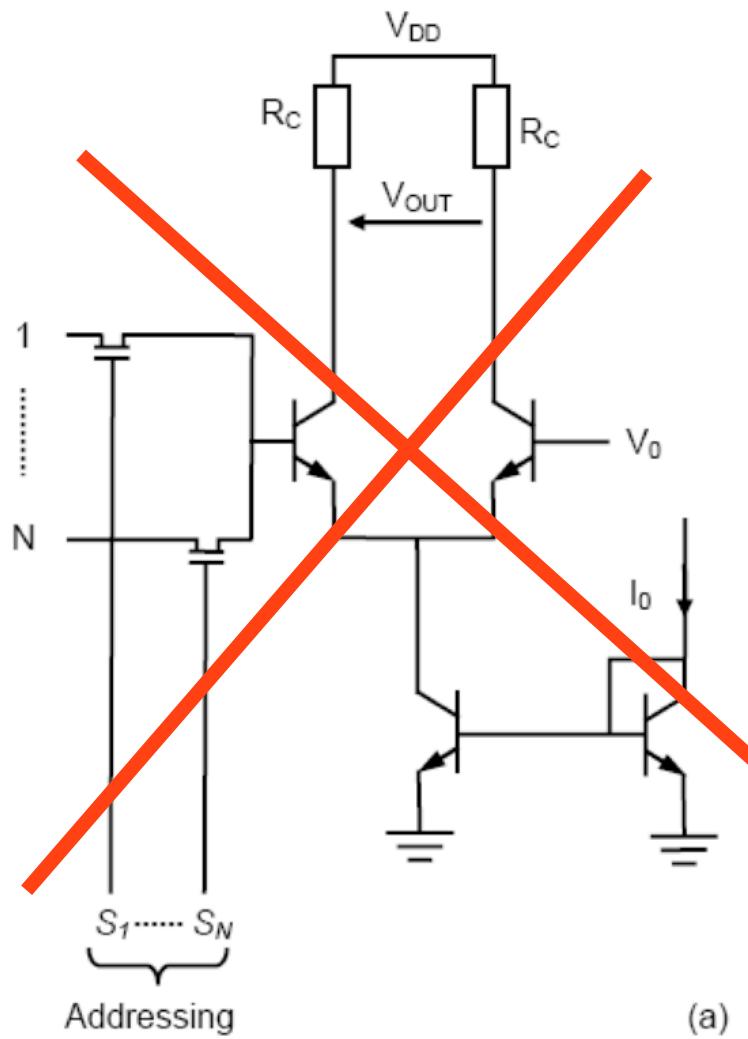


Cryogenic SiGe IC

- Digitally adjustable current source with **8 selectable current mirrors**
- High voltage gain LNA with **multiplexed inputs** to readout 3 columns of SQUIDs
- Digital circuit to **address** sequentially each pixel

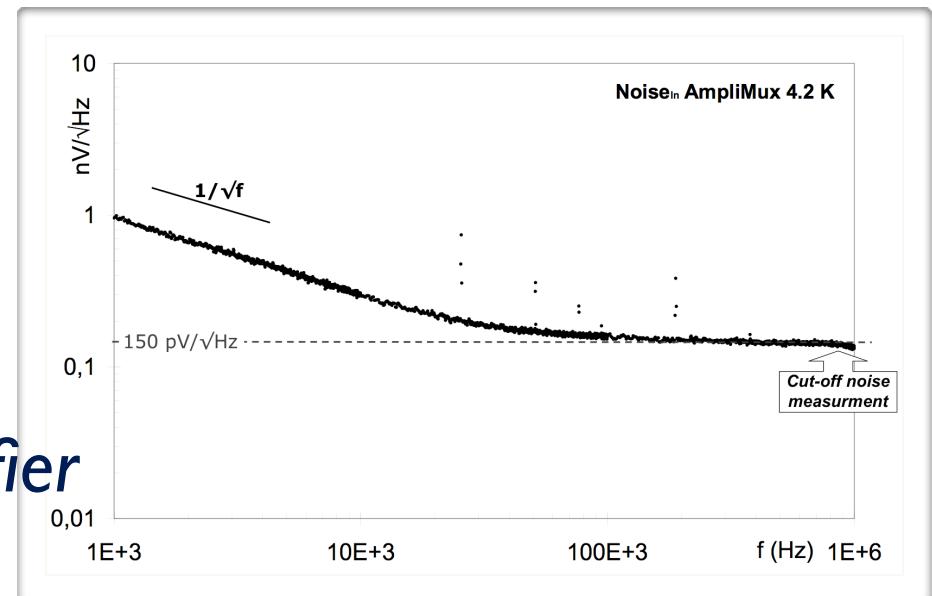
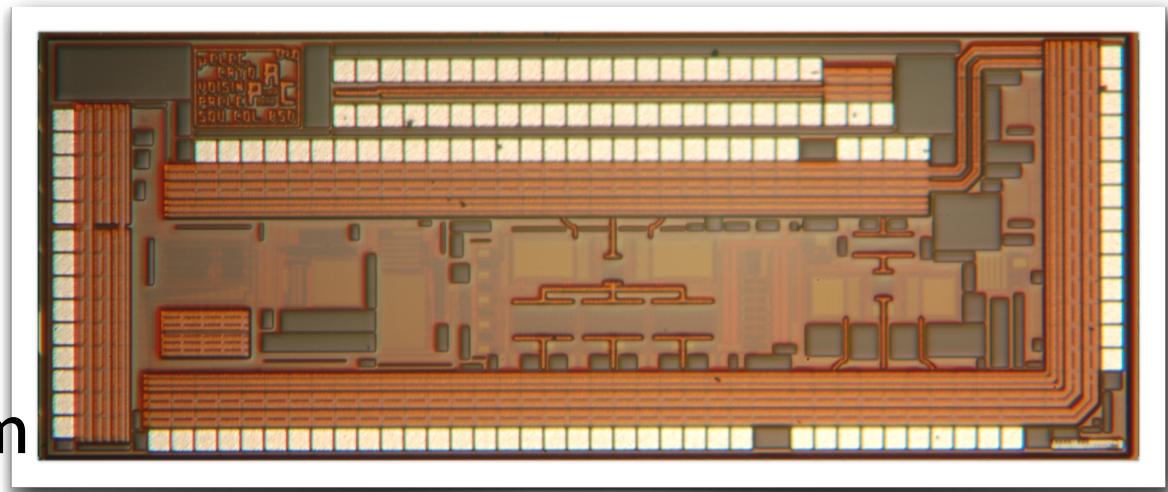


Multiplexing amplifier topology

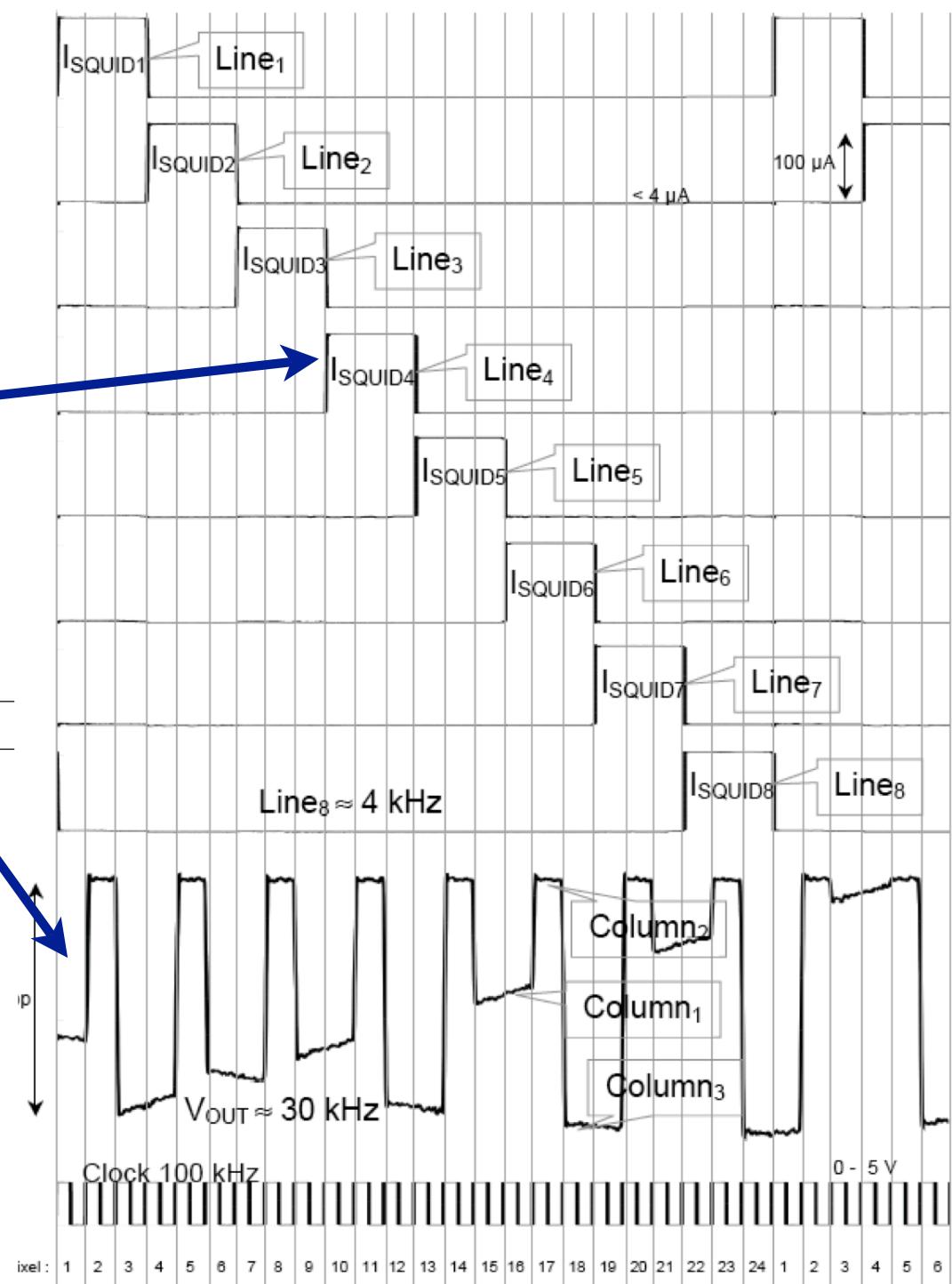
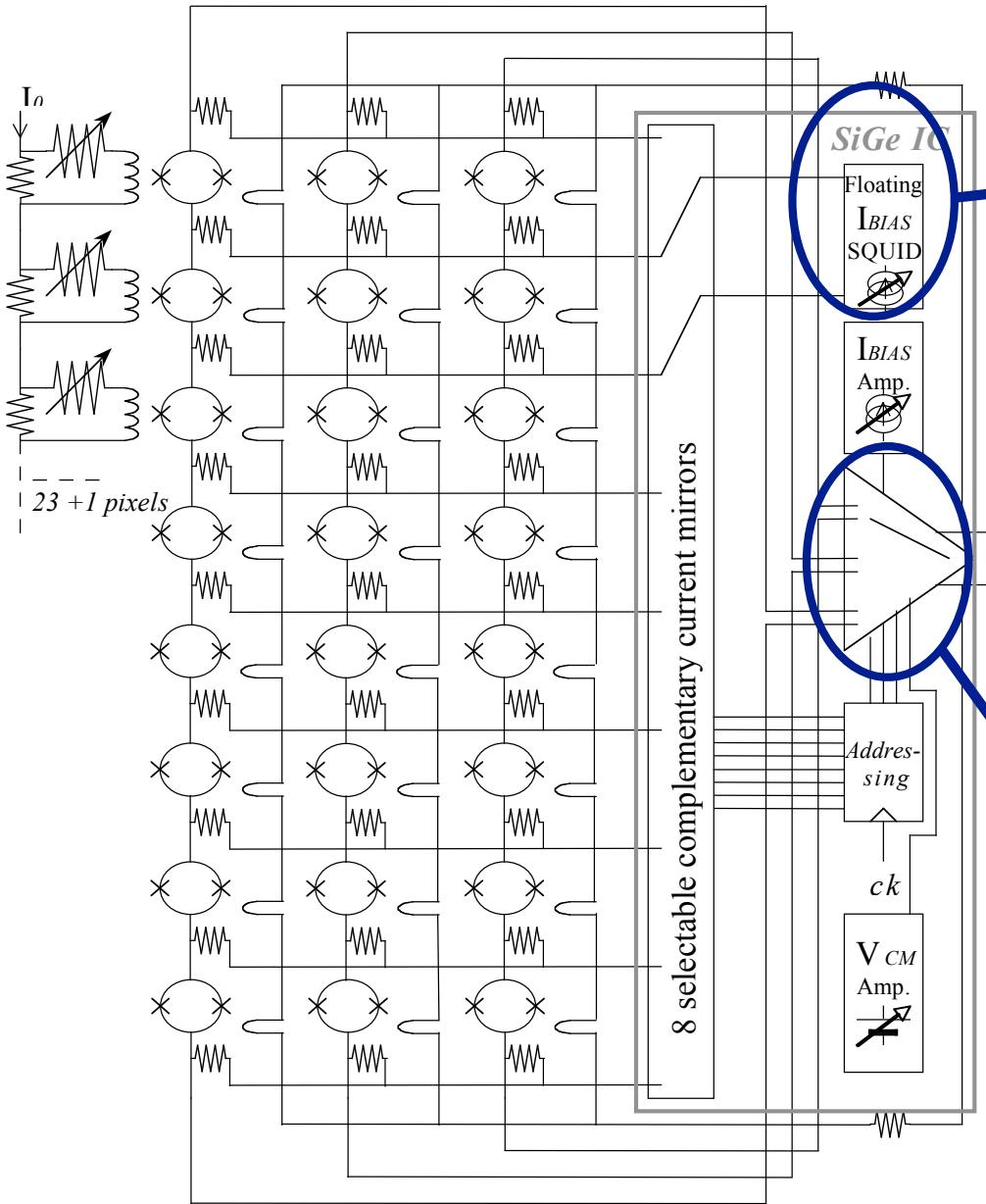


SiGe 0.35 AMS

- T operation range :
measured down to 2 K
- Dimension : 2 mm x 5 mm
- Input noise : 150 pV/ $\sqrt{\text{Hz}}$
- Multiplexing frequency : 10 MHz
- Power consumption : 15 mW
10 mW for the multiplexed LNA
5 mW for a second optional amplifier
100 μW for SQUID biasing
Few μW for digital addressing

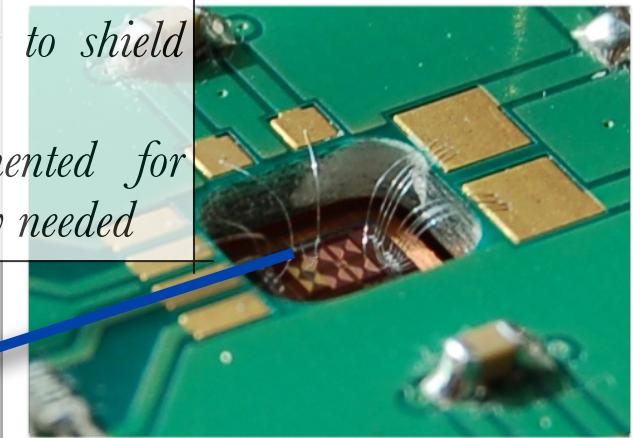
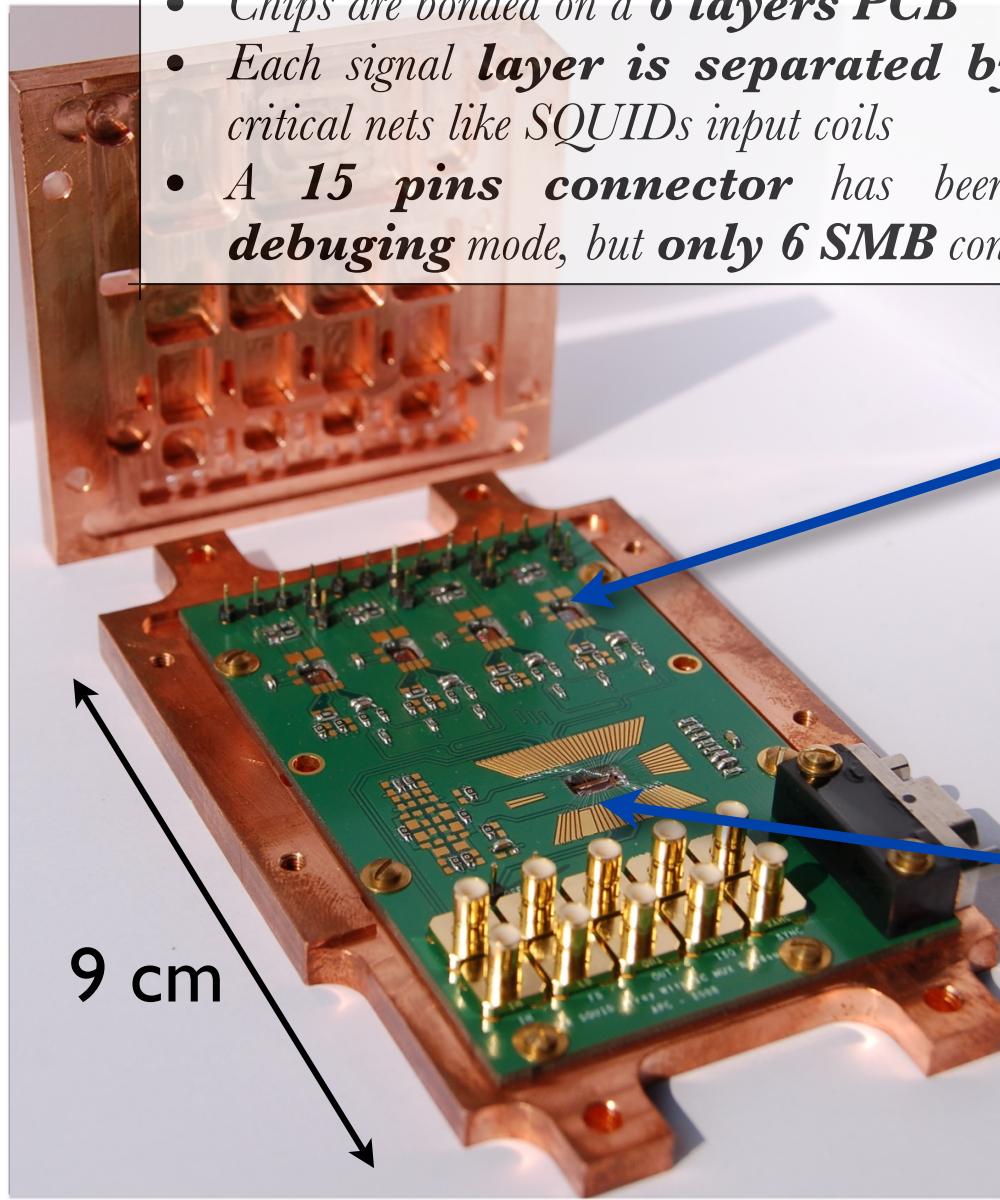


Cryogenic operation of the SiGe IC

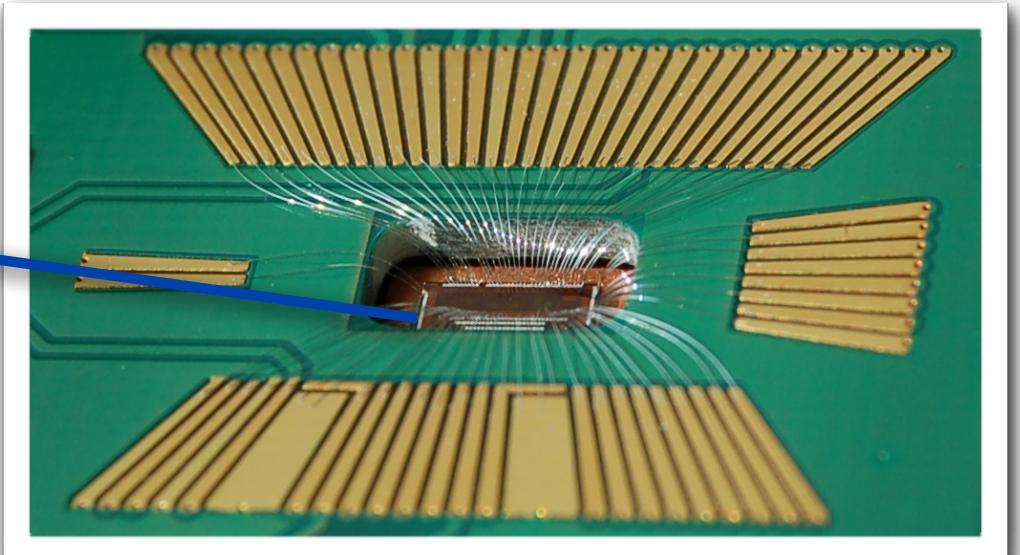


SiGe/SQUID Hybrid

- Chips are bonded on a **6 layers PCB**
- Each signal **layer is separated by GND plane** to shield critical nets like SQUIDs input coils
- A **15 pins connector** has been also implemented for **debuging mode**, but **only 6 SMB** connectors are realy needed



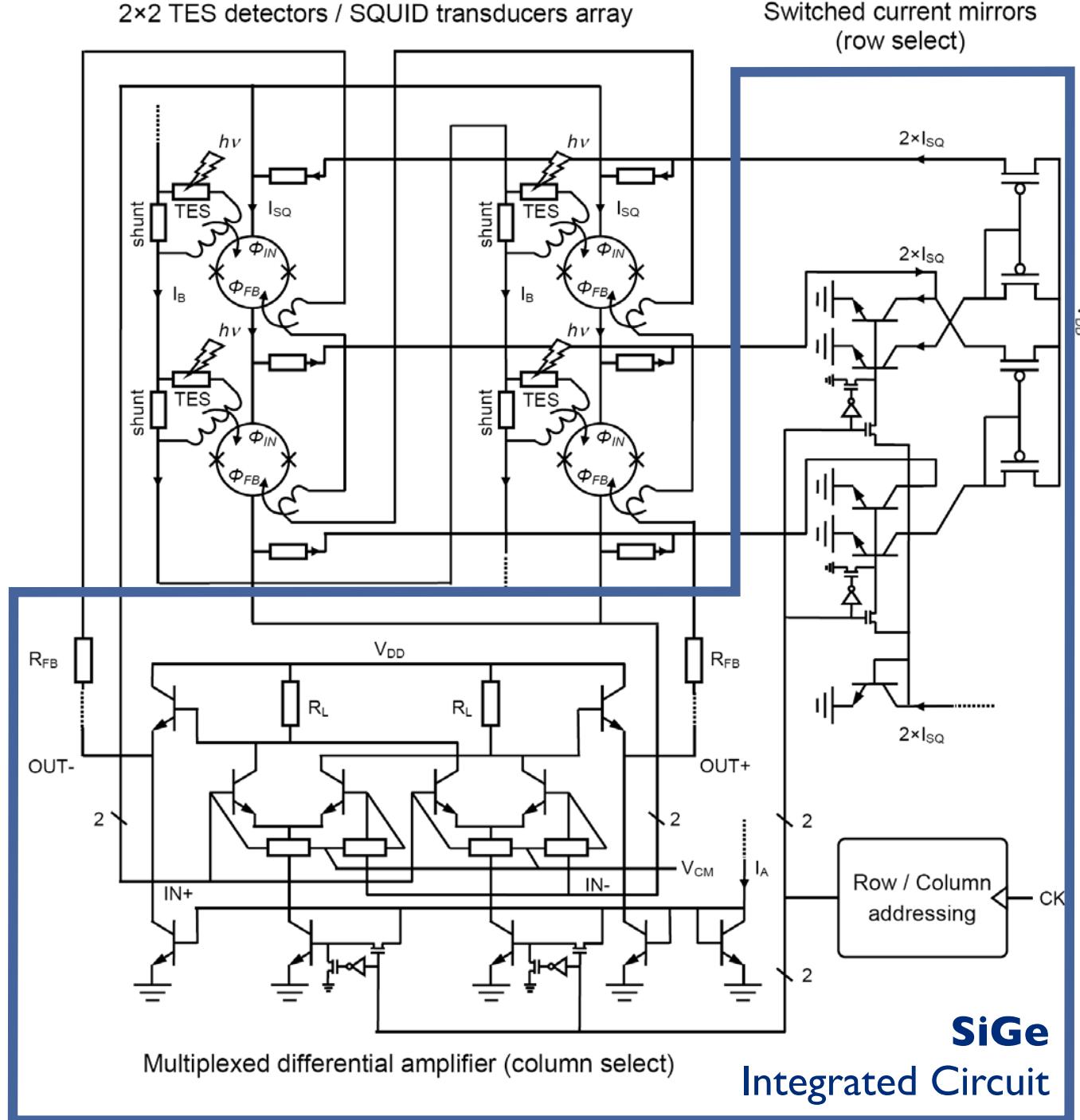
4 x SQ680 STARcryo



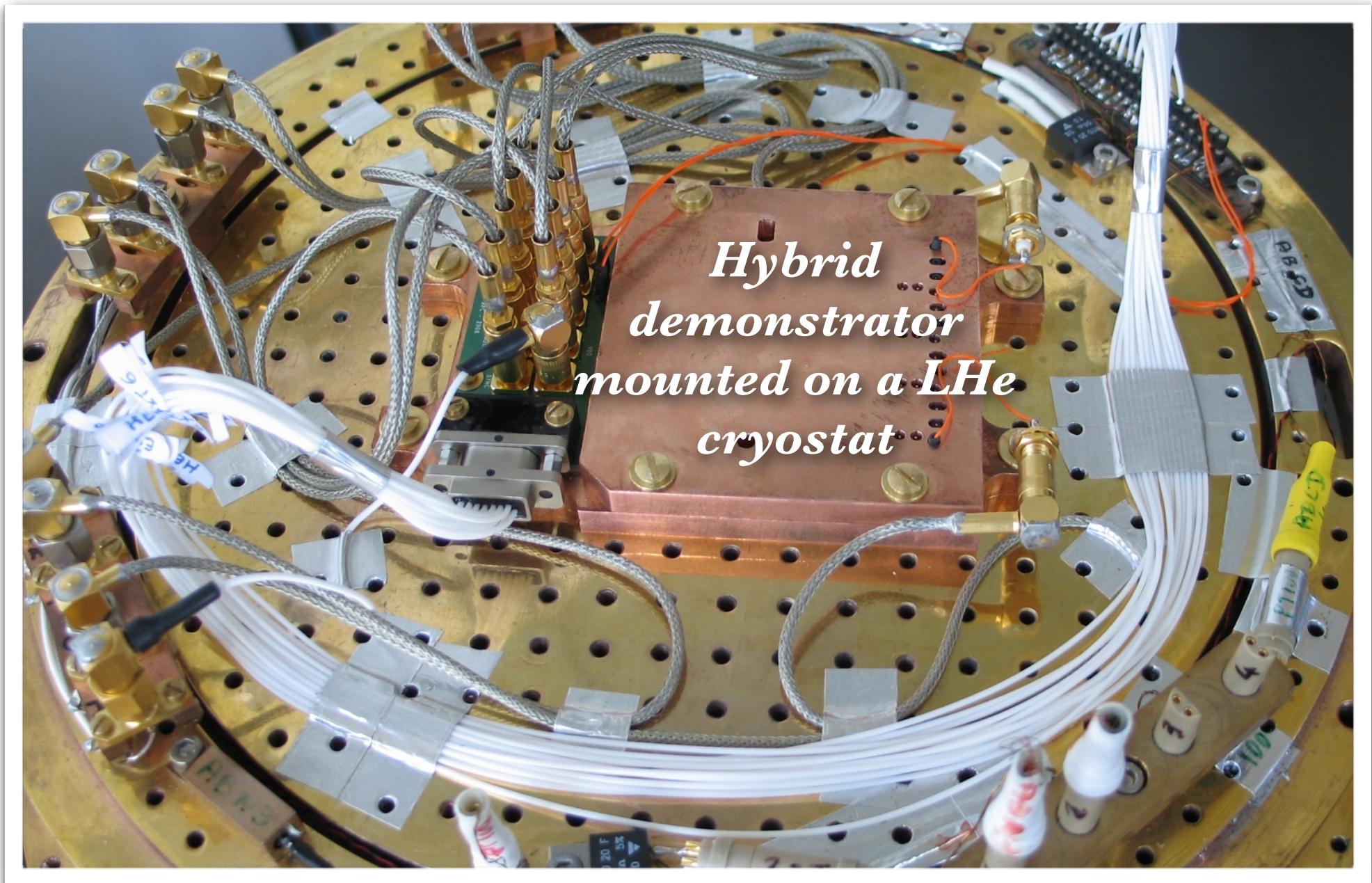
SiGe BiCMOS IC
uElec - La Londe - 2009

SiGe/SQUID Hybrid Demonstrator

scheme

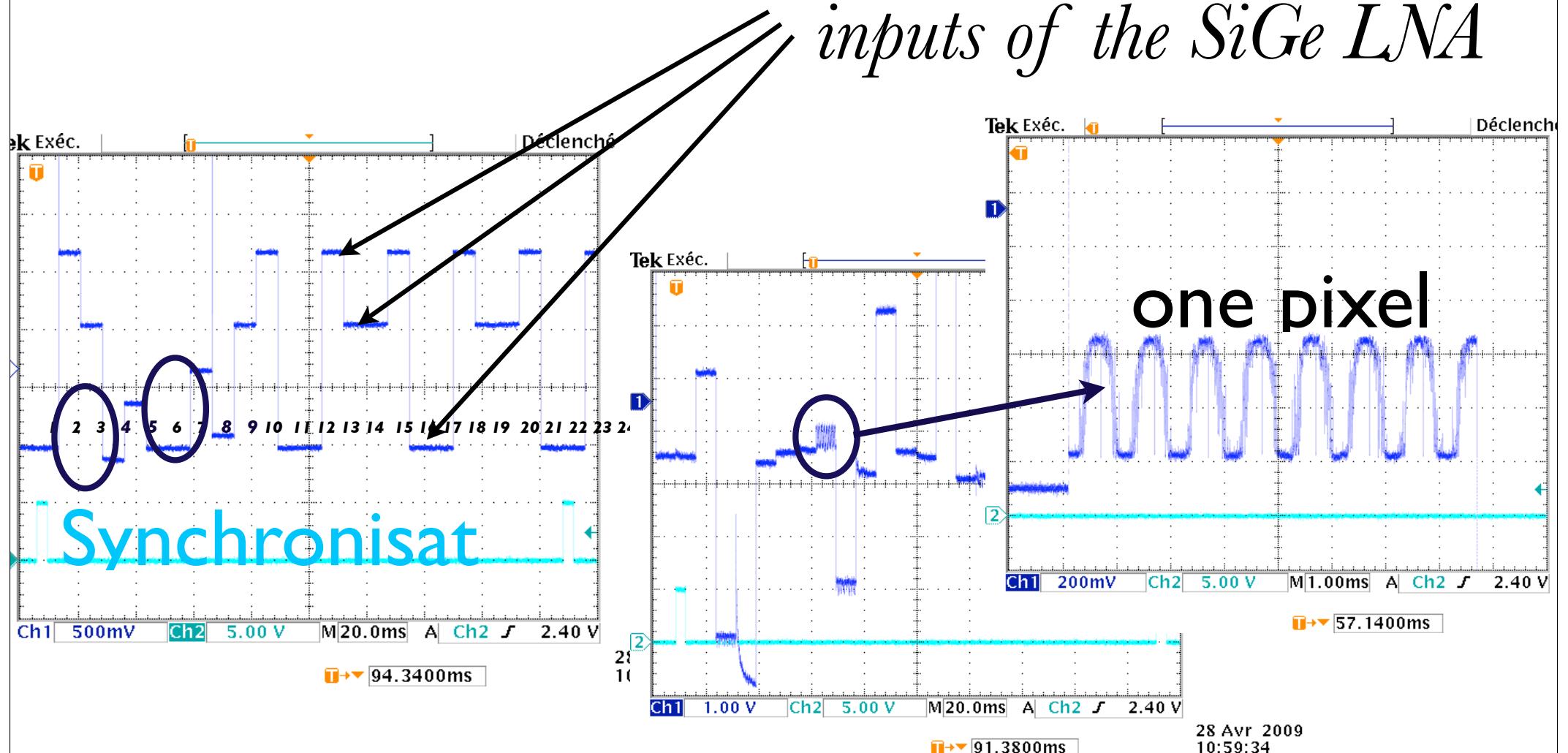


Under cryogenic measurements

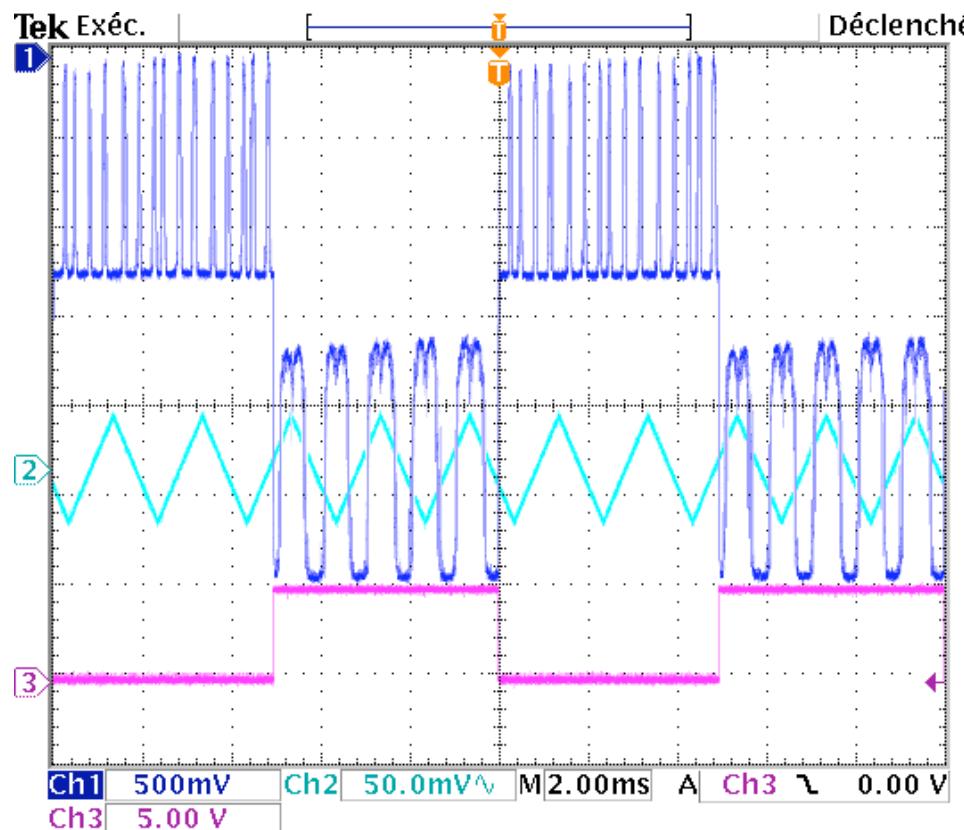


Multiplexing : 24 pixels

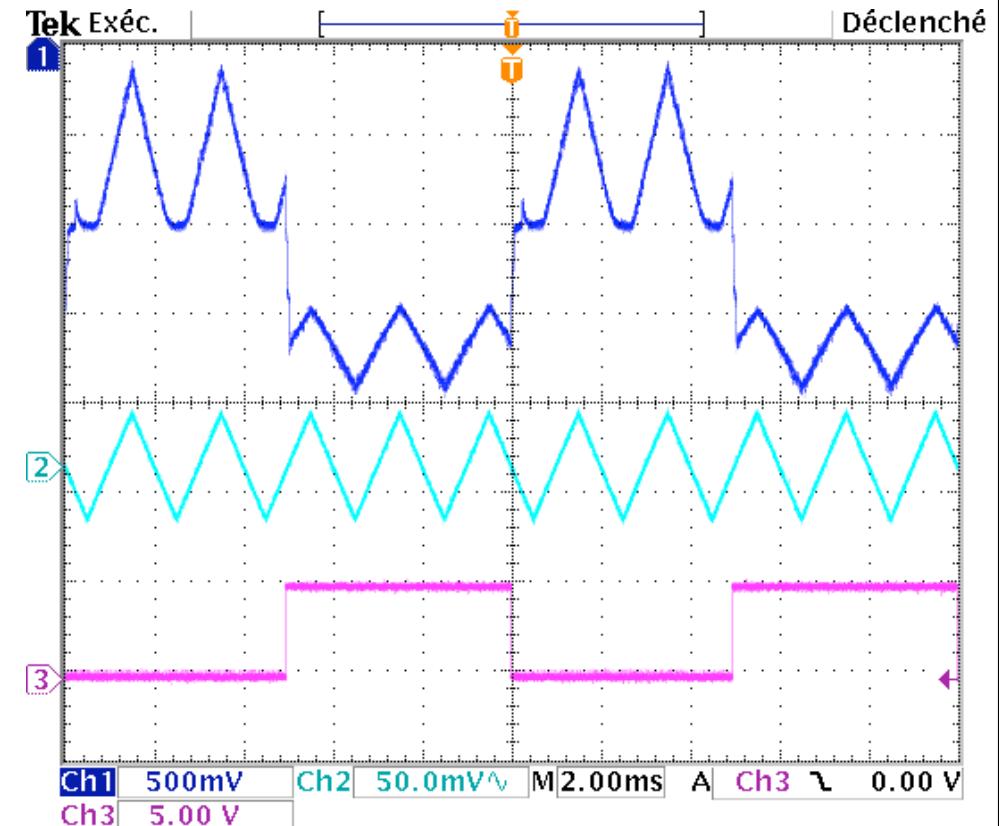
Steps are due to the DC offset of the tree multiplexed inputs of the SiGe LNA



Multiplexing : in open loop and with feedback (FLL)



Without FLL



With FLL

Architecture thermo-meca. pour matrice TES NbSi 23 pixels

